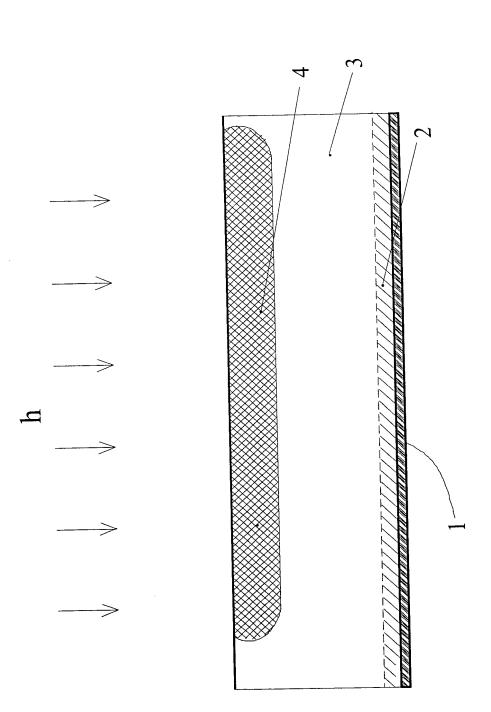
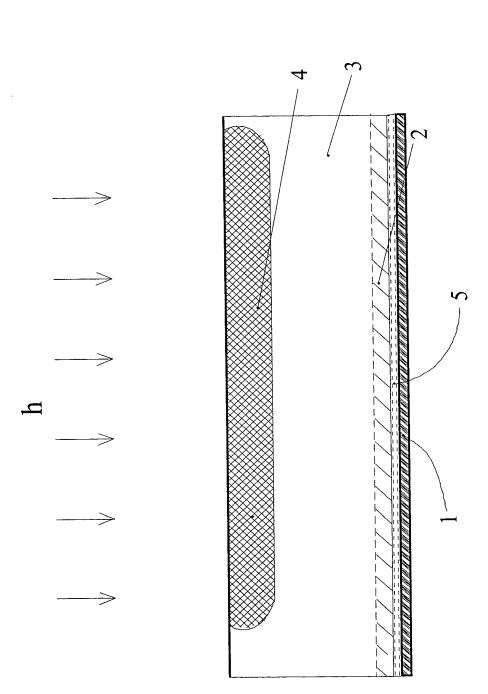
Blakely, Sokoloff, Taylor & Zafman LLP (714) 557-3800
Title: FAST SILICON PHOTODIODES WITH HIGH BACK SURFACE REFLECTANCE
IN A WAVELENGTH RANGE CLOSE TO THE BANDGAP
1st Named Inventor: Alexander O. Goushcha
Express Mail No.: EV323393842US
Docket No.: 2712P010
Sheet: 1 of 5



Blakely, Sokoloff, Taylor & Zafman LLP (714) 557-3800
Title: FAST SILICON PHOTODIODES WITH HIGH BACK SURFACE REFLECTANCE
IN A WAVELENGTH RANGE CLOSE TO THE BANDGAP

1st Named Inventor: Alexander O. Goushcha
Express Mail No.: EV323393842US
Docket No.: 2712P010
Sheet: 2 of 5



Blakely, Sokoloff, Taylor & Zafman LLP (714) 557-3800
Title: FAST SILICON PHOTODIODES WITH HIGH BACK SURFACE REFLECTANCE
IN A WAVELENGTH RANGE CLOSE TO THE BANDGAP
1st Named Inventor: Alexander O. Goushcha
Express Mail No.: EV323393842US
Docket No.: 2712P010
Sheet: 3 of 5

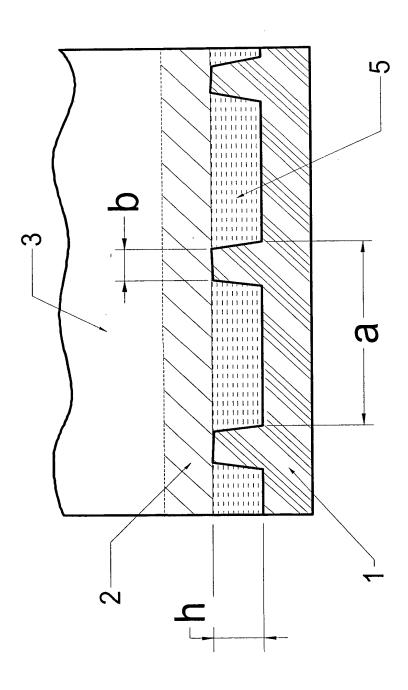
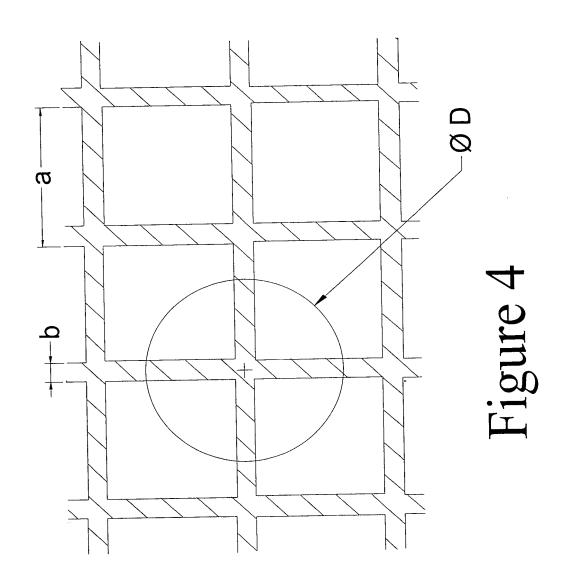


Figure 3

Blakely, Sokoloff, Taylor & Zafman LLP (714) 557-3800
Title: FAST SILICON PHOTODIODES WITH HIGH BACK SURFACE REFLECTANCE
IN A WAVELENGTH RANGE CLOSE TO THE BANDGAP

1st Named Inventor: Alexander O. Goushcha Express Mail No.: EV323393842US Sheet: 4 of 5

Docket No.: 2712P010



Blakely, Sokoloff, Taylor & Zafman LLP (714) 557-3800
Title: FAST SILICON PHOTODIODES WITH HIGH BACK SURFACE REFLECTANCE
IN A WAVELENGTH RANGE CLOSE TO THE BANDGAP
1st Named Inventor: Alexander O. Goushcha
Express Mail No.: EV323393842US
Docket No.: 2712P010
Sheet: 5 of 5

